

PEMD30

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

18 January 2023

Product data sheet

1. General description

NPN/PNP double Resistor-Equipped Transistor (RET) in an ultra small and flat lead SOT666 Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PEMH30 PNP/PNP complement: PEMB30

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplified circuit design
- · Reduces component count
- · Reduces pick and place costs

3. Applications

- Low current peripheral driver
- Cost-saving alternative for BC847BVN
- Controlling IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor; for the PNP transistor with negative polarity							
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)		[1]	1.54	2.2	2.86	kΩ

[1] See section "Test information" for resistor calculation and test conditions.



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	6 5 4	
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2		R1
6	O1	output (collector) TR1	1 2 3 SOT666	GND1 I1 O2 006aaa269

6. Ordering information

Table 3. Ordering information

Type number			
	Name	Description	Version
PEMD30	SOT666	plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<u>SOT666</u>

7. Marking

Table 4. Marking codes

Type number	Marking code
PEMD30	2U

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit	
Per transistor; for the PNP transistor with negative polarity							
V _{CBO}	collector-base voltage	open emitter		-	50	V	
V _{CEO}	collector-emitter voltage	open base		-	50	V	
V _{EBO}	emitter-base voltage	open collector		-	5	V	
Io	output current			-	100	mA	
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	200	mW	
Per device							
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	300	mW	
Tj	junction temperature			-	150	°C	
T _{amb}	ambient temperature			-65	150	°C	
T _{stg}	storage temperature			-65	150	°C	

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.

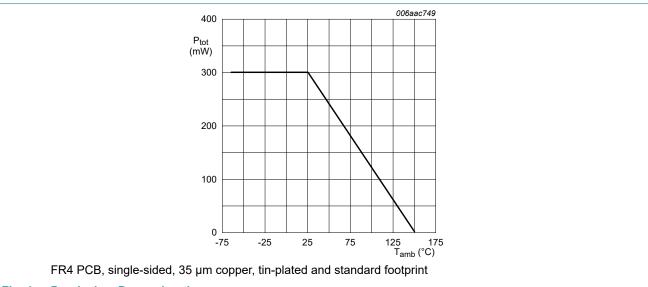


Fig. 1. Per device: Power derating curve

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	416	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.

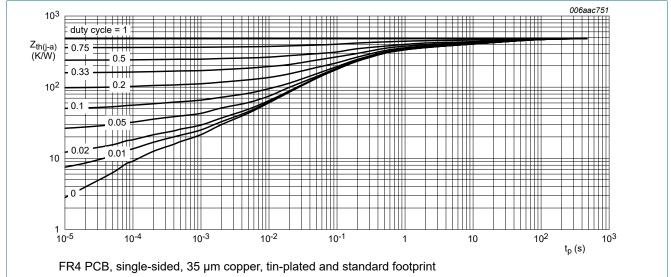


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

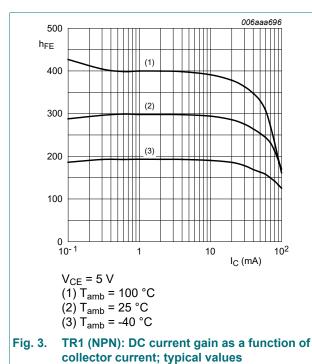
50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

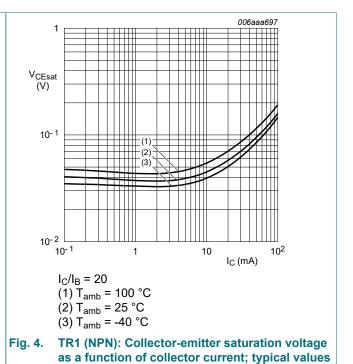
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or; for the PNP transistor	with negative polarity					
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	100	nA
I _{CEO} co	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	1	μΑ
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 20 mA; T _{amb} = 25 °C		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	150	mV
R1	bias resistor 1 (input)		[1]	1.54	2.2	2.86	kΩ
TR1 (NPN)	'						
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.5	pF
TR2 (PNP)							
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	-	3	pF
		1					

[1] See section "Test information" for resistor calculation and test conditions.





Product data sheet

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

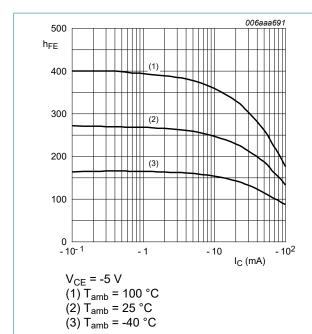


Fig. 5. TR2 (PNP): DC current gain as a function of collector current; typical values

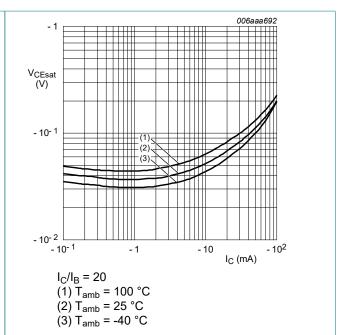


Fig. 6. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

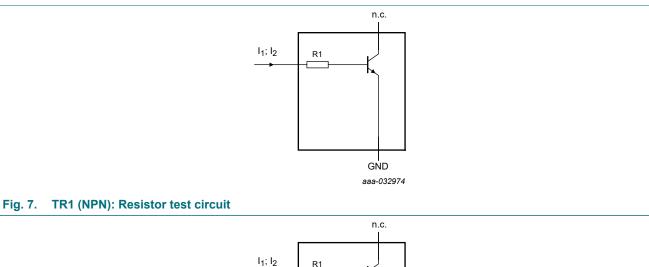
50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

11. Test information

Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_I = \frac{V(I_2) - V(I_I)}{I_2 - I_I}$$



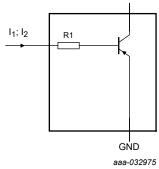


Fig. 8. TR2 (PNP): Resistor test circuit

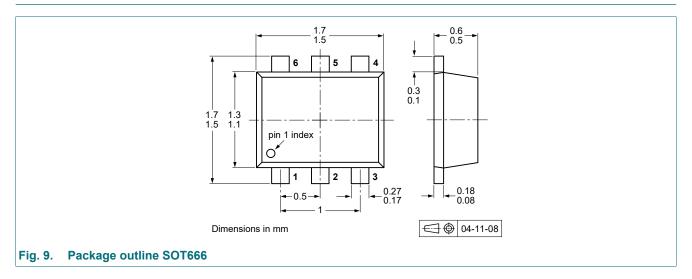
Resistor test conditions

Table 8. Resistor test conditions

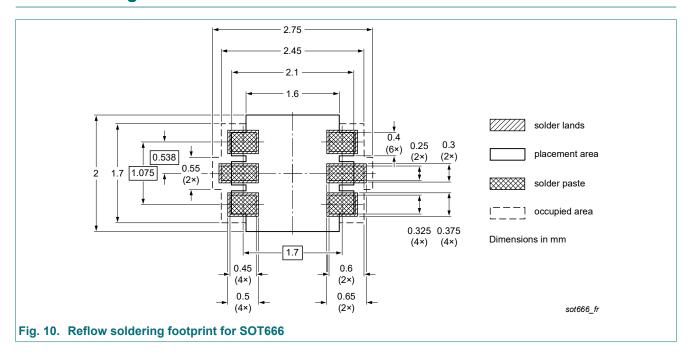
PEMD30	R1 (kΩ)	R2 (kΩ)	Test conditions	
			l ₁	l ₂
TR1 (NPN)	2.2	open	750 μΑ	950 μΑ
TR2 (PNP)	2.2	open	-750 μΑ	-950 μΑ

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

12. Package outline



13. Soldering



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14. Revision history

Table 9. Revision history

table 3. Nevision instory							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PEMD30 v.2	20230118	Product data sheet	-	PEMD30_PUMD30 v.1			
Modifications:	Nexperia. Legal texts have bee Family data sheet re	ta sheet has been redesion adapted to the new conduced to single type data to non-automotive qualification	mpany name where appr sheet.	7.0			
PEMD30_PUMD30 v.1	20060331	Product data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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